

DATE: 22/05/2018

ADVERTISEMENT

Applications are invited for filling up the following post under the project entitled: **Development of Highly Sensitive Photo-detector based on “Dielectrophoretic Assembly of TiS₃ Nanoribbons”** sponsored by Science and Engineering Research Board(SERB), Govt. of India.

Name & No. of post

1. Junior Research Fellow (JRF) (01)

MINIMUM QUALIFICATIONS & REMUNERATIONS:

M. Tech. in Nanoscience and Nanotechnology, Optoelectronics, Electronics and communication & Material science with 60% marks or equivalent CGPA.

or

M.Sc. with NET qualification in Electronics, Physics, Chemistry, Nanoscience, Nanotechnology with 60% marks or equivalent CGPA.

Remuneration: As per SERB norms.

Desirable Qualifications:

Preference will be given to those candidates having at 06 months research experience on 2D materials and dielectrophoretic depositions.

Candidate(s) possessing the requisite qualifications send their applications through email(pmishra@jmi.ac.in) to the Principal Investigator by **15th June, 2018** giving complete bio-data (with e-mail address and mobile no.)



Dr. Prabhash Mishra,
Principal Investigator
Centre for Nanoscience and Nanotechnology, JMI.
E-mail : pmishra@jmi.ac.in